

ENGLA00261A

Rev. V1

Features

Operation Across 13 - 26 GHz

Small Signal Gain: 7 dB

• Noise Figure: 2.5 dB

I/O Return Loss: 13.5 dB or better

OIP3: 24 to 29 dBm

· Die Size:

1.40 x 1.41 mm 1.54 sq. mm 0.055 x 0.056 inch

RoHS* Compliant

Applications

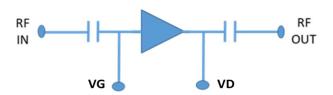
- Ku- & K-Band radar / driver amplifier functions; SATCOM
- Radio receivers / transmitters when biased for linearity
- · Test & Measurement Systems

Description

The ENGLA00261A is a wideband pHEMT two-stage 7 dB gain low noise distributed amplifier, operating across 13 to 26 GHz. The design is 50 ohm matched. The LNA has a typical noise figure of 2.5 dB across 13 to 26 GHz, at room temperature. Output third-order intercept point (OIP3) is typically above 25 dBm. The amplifier has gold backside metallization and is designed for gold-tin eutectic or high thermal conductivity silver epoxy attachment.

Functional Block Diagram

MMIC RF ports are DC-blocked. RF ports designed for 50 ohms.



Ordering Information

Part Number	Package		
ENGLA00261A	Die		

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



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Electrical Specifications:

Freq. = 13 - $2\dot{6}$ GHz, T_A = +25°C, VD = 5.0 V; IDS = 19 mA (Iq), VG ~ +0.6 V

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Small Signal Gain	_	dB	6.5	7.2	_
Noise Figure	_	dB	_	2.5	3.0
Input Return Loss	_	dB	12	16	_
Output Return Loss	_	dB	12	14	_
Output IP3	_	dBm	_	28	_
Supply Current	_	mA	_	19	25
Thermal Resistance	includes 25-µm thick AuSn solder mount	°C/W	_	700	_

Recommended Operating Conditions

Parameter	Min.	Тур.	Max.	Units
Drain Voltage		5	6	V
Gate Voltage		0.6	1.0	V
Quiescent Drain Current		19	25	mA

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Absolute Maximum Ratings^{1,2}

Parameter	Absolute Maximum			
Drain Voltage	6 V			
Gate Voltage	1.2 V			
RF Input Power	20 dBm			
Operating Temperature	-55°C to +100°C			
Storage Temperature	-65°C to +150°C			

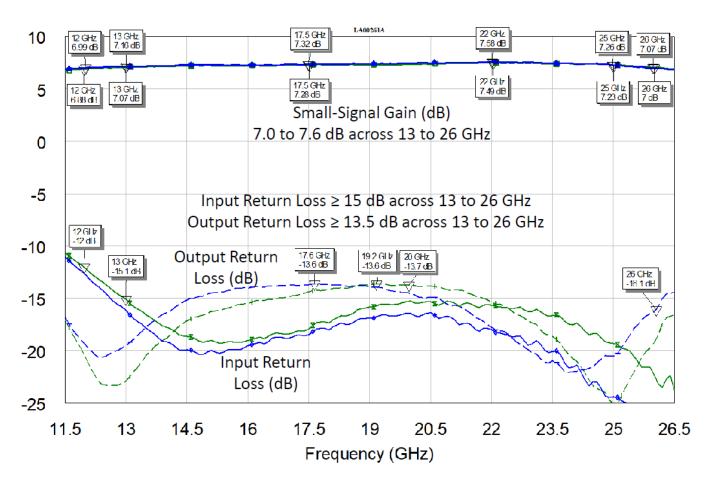
- Exceeding any one or combination of these limits may cause permanent damage to this device.
- MACOM does not recommend sustained operation near these survivability limits.



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Measured RF Data: With Wirebonds and External Microstrip Flares

Gain and In / Out Return Loss (for two LA00261A amplifiers): T = 25 °C, VD = 3.0 V, IQ = 19 mA, VG = 0.6 V

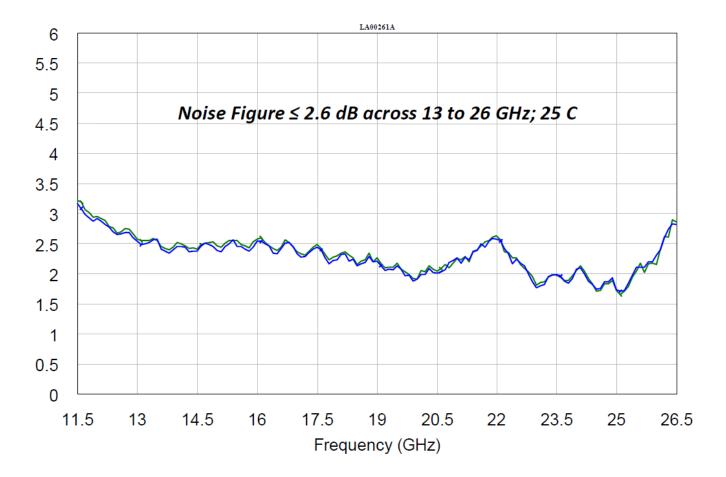




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Measured RF Data: With Wirebonds and External Microstrip Flares

Noise Figure (for two LA00261A amplifiers): T = 25 °C, VD = 3.0 V, IQ = 19 mA, VG = 0.6 V





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Measured RF Data: With Wirebonds and External Microstrip Flares

S-Parameters: $T_A = +25$ °C, VD = 5.0 V; IDS = 19 mA (Iq), $VG \sim +0.6 \text{ V}$

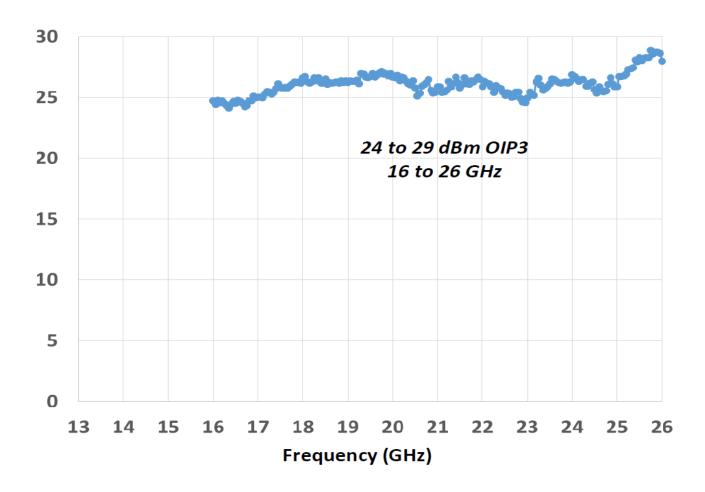
	S11	S11	S21	S21	S12	S12	S22	S22
Frequency (GHz)	mag	angle	mag	angle	mag	angle	mag	angle
(0112)	(dB)	(deg	(dB)	(deg	(dB)	(deg	(dB)	(deg
13	-16.18	52.89	7.16	-3.67	-14.30	-84.23	-19.54	-134.30
13.5	-17.87	56.39	7.19	-15.75	-14.28	-94.29	-17.72	-130.24
14	-19.16	62.79	7.22	-27.71	-14.25	-103.93	-16.40	-134.57
14.5	-19.95	70.85	7.26	-39.39	-14.21	-113.21	-15.17	-142.35
15	-20.17	78.61	7.29	-51.03	-14.22	-122.26	-14.61	-152.62
15.5	-19.93	83.93	7.23	-62.35	-14.17	-131.33	-14.28	-162.43
16	-19.54	88.73	7.26	-73.48	-14.23	-139.24	-14.03	-173.28
16.5	-19.14	91.70	7.27	-84.34	-14.15	-147.29	-13.83	176.26
17	-18.80	90.93	7.30	-95.06	-14.07	-155.41	-13.75	163.92
17.5	-18.49	92.38	7.31	-105.75	-13.96	-164.00	-13.70	151.55
18	-18.04	91.06	7.41	-116.86	-13.92	-171.91	-13.73	137.76
18.5	-17.51	88.75	7.41	-127.43	-13.83	-179.97	-13.89	125.06
19	-16.86	85.06	7.37	-138.38	-13.76	171.78	-13.92	111.29
19.5	-16.73	81.57	7.43	-148.74	-13.75	164.35	-14.27	96.91
20	-16.46	77.49	7.43	-159.46	-13.64	156.43	-14.53	83.34
20.5	-16.38	72.64	7.46	-170.49	-13.53	148.04	-14.88	66.96
21	-16.80	66.10	7.49	179.26	-13.45	140.44	-15.74	49.67
21.5	-17.55	60.38	7.50	168.38	-13.43	132.77	-16.51	32.04
22	-18.00	57.36	7.58	157.36	-13.28	125.24	-17.79	14.23
22.5	-18.71	53.13	7.52	146.28	-13.24	117.28	-18.78	-7.04
23	-19.35	49.98	7.55	135.38	-13.09	109.57	-20.21	-27.41
23.5	-20.11	45.93	7.45	124.50	-13.07	101.21	-20.98	-55.79
24	-21.56	43.49	7.43	113.04	-13.01	93.41	-22.04	-87.33
24.5	-22.97	44.67	7.39	102.53	-12.90	85.80	-21.56	-125.11
25	-24.43	45.93	7.23	91.01	-12.81	78.72	-20.54	-157.06
25.5	-26.41	38.83	7.11	79.91	-12.63	71.09	-17.94	178.64
26	-28.83	46.28	7.00	69.34	-12.54	62.73	-16.30	159.66



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Measured RF Data: With Wirebonds and External Microstrip Flares

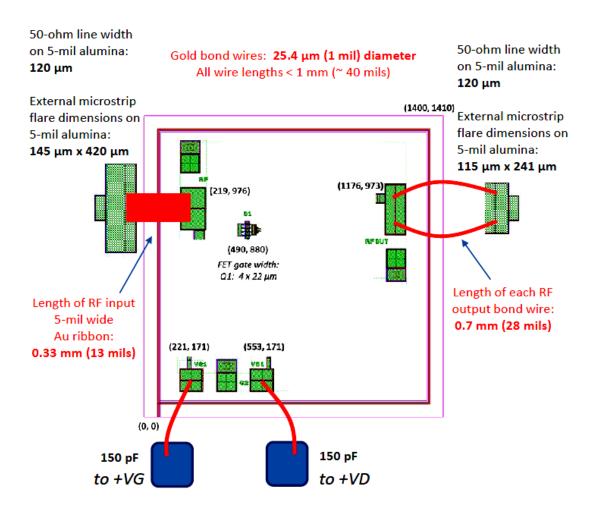
Output Third-Order Intercept Point: T = 25 °C, VD = 3.0 V, IQ = 27 mA, VG = 0.56 V





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MMIC Assembly Drawing: External Microstrip Flares, 150 pF Bypass Capacitors, & Bond Wires



Assembly Comments

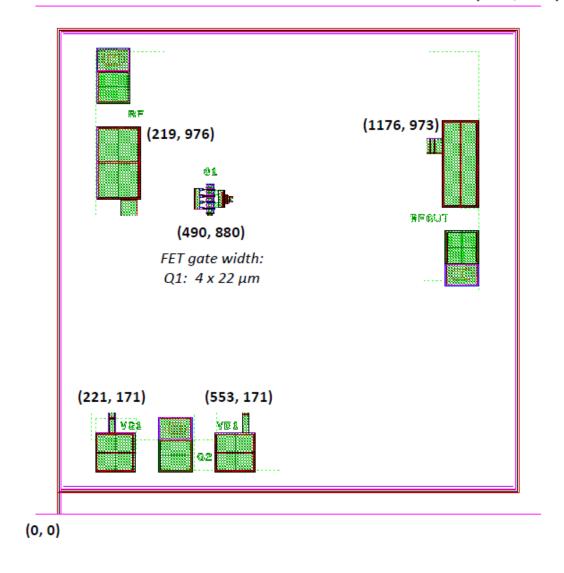
- 1. If mounting the MMIC using either AuSn solder, or high thermal conductivity silver epoxy, the regions underneath the FET heat sources should be void free. Even small voids underneath the FETs could cause FET channel temperature to significantly increase.
- 2. RF ports are DC blocked.
- 3. At X-band, RF I/O port impedances are near 50 ohms.



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Outline Drawing – MMIC Dimensions: 1.40 mm x 1.41 mm FET (heat source) and bond pad center coordinates shown (µm)

(1400, 1410)



Notes

- 1. All dimensions are given in micrometers (μm) unless specified. Typ. tolerance: +25 μm / -25 μm .
- 2. GaAs thickness (excluding front side/back side metallization): 75 μm. Typical tolerance +/- 8 μm.
- 3. Backside metallization is gold.
- 4. Bond pad metallization is gold.



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